

Hyper TOPLED® Hyper-Bright LED

LB T673, LV T673, LT T673



LV T673 abgekündigt nach PD_078_02 - wird durch
LV T67C ersetzt werden
LV T673 obsolete acc. to PD_078_02 - will be
replaced by LV T67C

Besondere Merkmale

- **Gehäusetyyp:** weißes P-LCC-2 Gehäuse
- **Besonderheit des Bauteils:** extrem breite Abstrahlcharakteristik; ideal für Hinterleuchtungen und Einkopplungen in Lichtleiter
- **Wellenlänge:** 470 nm (blau), 505 nm (verde), 528 nm (true green)
- **Abstrahlwinkel:** Lambertscher Strahler (120°)
- **Technologie:** InGaN
- **optischer Wirkungsgrad:** 2 lm/W (blau), 6 lm/W (verde), 8 lm/W (true green)
- **Gruppierungsparameter:** Lichtstärke, Wellenlänge
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 2000/Rolle, ø180 mm oder 8000/Rolle, ø330 mm
- **ESD-Festigkeit:** ESD-sicher bis 2 kV nach EOS/ESD-5.1-1993

Anwendungen

- Ampelanwendung
- Informationsanzeigen im Außenbereich
- optischer Indikator
- Hinterleuchtung (LCD, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u. ä.)
- Markierungsbeleuchtung (z.B. Stufen, Fluchtwege, u.ä.)
- Signal- und Symbolleuchten
- Scanner

Features

- **package:** white P-LCC-2 package
- **feature of the device:** extremely wide viewing angle; ideal for backlighting and coupling in light guides
- **wavelength:** 470 nm (blue), 505 nm (verde), 528 nm (true green)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** InGaN
- **optical efficiency:** 2 lm/W (blue), 6 lm/W (verde), 8 lm/W (true green)
- **grouping parameter:** luminous intensity, wavelength
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 2000/reel, ø180 mm or 8000/reel, ø330 mm
- **ESD-withstand voltage:** up to 2 kV acc. to EOS/ESD-5.1-1993

Applications

- traffic lights
- outdoor displays
- optical indicators
- backlighting (LCD, switches, keys, displays, illuminated advertising, general lighting)
- interior automotive lighting (e.g. dashboard backlighting, etc.)
- marker lights (e.g. steps, exit ways, etc.)
- signal and symbol luminaire
- scanners

Typ	Emissions- farbe	Farbe der Lichtaustritts- fläche	Lichtstärke	Lichtstrom	Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 20 \text{ mA}$ $I_V \text{ (mcd)}$	Luminous Flux $I_F = 20 \text{ mA}$ $\Phi_V \text{ (mlm)}$	Ordering Code
LB T673-N1P1-35 LB T673-P1Q2-35	blue	colorless clear	28.0 ... 56.0 45.0 ... 112.0	120 (typ.) 230 (typ.)	Q65110A0545 Q65110A0546
■ LV T673-Q1R1-35 ■ LV T673-R1S2-35	verde	colorless clear	71.0 ... 140.0 112.0 ... 280.0	310 (typ.) 560 (typ.)	Q62703Q4845 Q62703Q4891
LT T673-Q2R2-35 LT T673-R2T1-35	true green	colorless clear	90.0 ... 180.0 140.0 ... 355.0	390 (typ.) 700 (typ.)	Q62703Q4851 Q62703Q4895

- LV T673 abgekündigt nach PD_078_02 - wird durch LV T67C ersetzt werden
 LV T673 obsolete acc. to PD_078_02 - will be replaced by LV T67C
 Letzte Bestellung / Last Order: 30.09.2003
 Letzte Lieferung / Last Delivery: 31.03.2004

Anm.: -35 gesamter Farbbereich, Lieferung in Einzelgruppen (siehe **Seite 5**)

*Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe, die aus nur 3 bzw. 4 Halbgruppen besteht. Einzelne Halbgruppen sind nicht erhältlich.
 In einer Verpackungseinheit / Gurt ist immer nur eine Halbgruppe enthalten.*

Note: -35 Total color tolerance range, delivery in single groups (please see **page 5**)

*The standard shipping format for serial types includes a lower or upper family group of 3 or 4 individual groups. Individual half groups are not available.
 No packing unit / tape ever contains more than one luminous intensity half group.*

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LB	LV, LT	
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_j	+ 110	+ 125	°C
Durchlassstrom Forward current	I_F	20		mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	200	250	mA
Sperrspannung ¹⁾ Reverse voltage	V_R	5		V
Leistungsaufnahme Power consumption $T_A \leq 25 \text{ °C}$	P_{tot}	80		mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient	$R_{th JA}$	400		K/W
Sperrschicht/Lötpad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)	$R_{th JS}$	180		K/W

¹⁾ für kurzzeitigen Betrieb geeignet / suitable for short term application

Kennwerte ($T_A = 25\text{ °C}$)**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LB	LV	LT	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 20\text{ mA}$	λ_{peak}	465	503	523	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength $I_F = 20\text{ mA}$	λ_{dom}	470 ± 6	505 ± 7	528 ± 9	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20\text{ mA}$	$\Delta\lambda$	25	30	33	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	120	120	120	Grad deg.
Durchlassspannung ²⁾ (min.) Forward voltage (typ.) $I_F = 20\text{ mA}$ (max.)	V_F	2.9	2.9	2.9	V
	V_F	3.5	3.3	3.3	V
	V_F	3.9	3.9	3.9	V
Sperrstrom (typ.) Reverse current (max.) $V_R = 5\text{ V}$	I_R	0.01	0.01	0.01	μA
	I_R	10	10	10	μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.04	0.03	0.04	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.03	0.04	0.04	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 4.5	- 3.6	- 3.6	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 20\text{ mA}$	η_{opt}	2	6	8	lm/W

¹⁾ Wellenlängengruppen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelength groups are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Durchlassspannungsgruppen werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Forward voltage groups are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

1) Wellenlängengruppen / Wavelength groups

Gruppe Group	blue		verde		true green		Einheit Unit
	min.	max.	min.	max.	min.	max.	
3	464	468	498	503	519	525	nm
4	468	472	503	507	525	531	nm
5	472	476	507	512	531	537	nm

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_V (mcd)	Lichtstrom Luminous Flux Φ_V (lm)
N1	28.0 ... 35.5	95 (typ.)
N2	35.5 ... 45.0	120 (typ.)
P1	45.0 ... 56.0	150 (typ.)
P2	56.0 ... 71.0	190 (typ.)
Q1	71.0 ... 90.0	240 (typ.)
Q2	90.0 ... 112.0	300 (typ.)
R1	112.0 ... 140.0	380 (typ.)
R2	140.0 ... 180.0	480 (typ.)
S1	180.0 ... 224.0	600 (typ.)
S2	224.0 ... 280.0	760 (typ.)
T1	280.0 ... 355.0	950 (typ.)

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
 Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Gruppenbezeichnung auf Etikett
Group Name on Label

Beispiel: S2-3

Example: S2-3

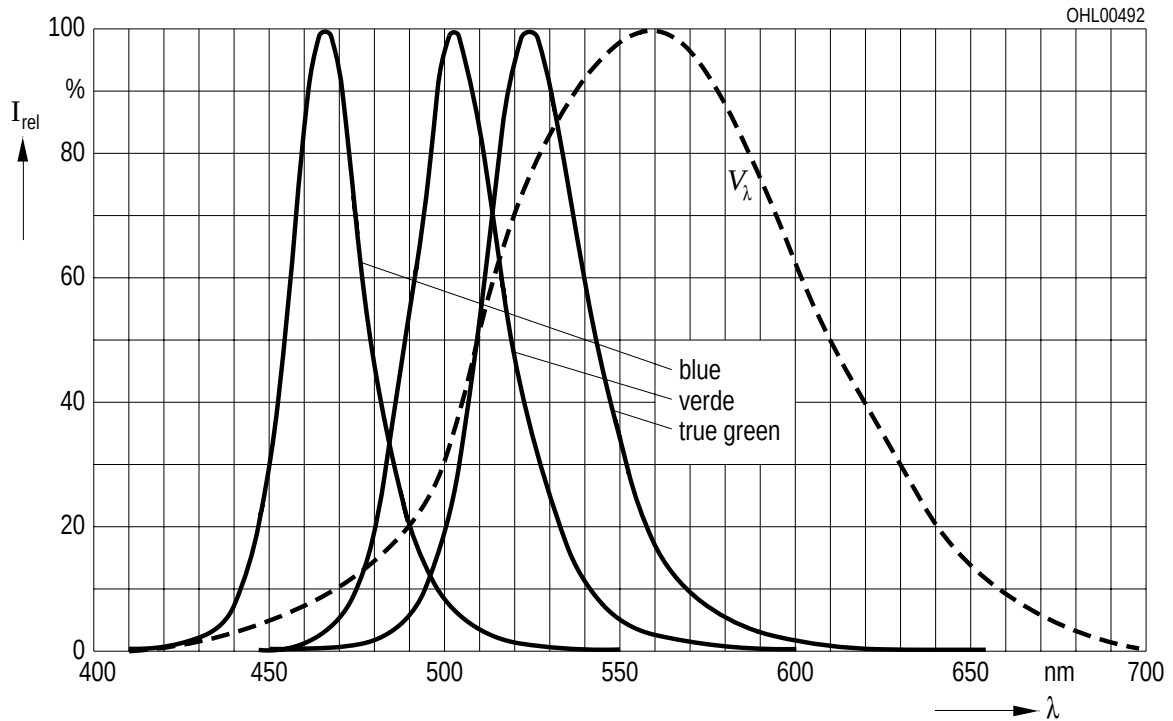
Lichtgruppe Luminous Intensity Group	Halbgruppe Half Group	Wellenlänge Wavelength
S	2	3

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 20\text{ mA}$

Relative Spectral Emission

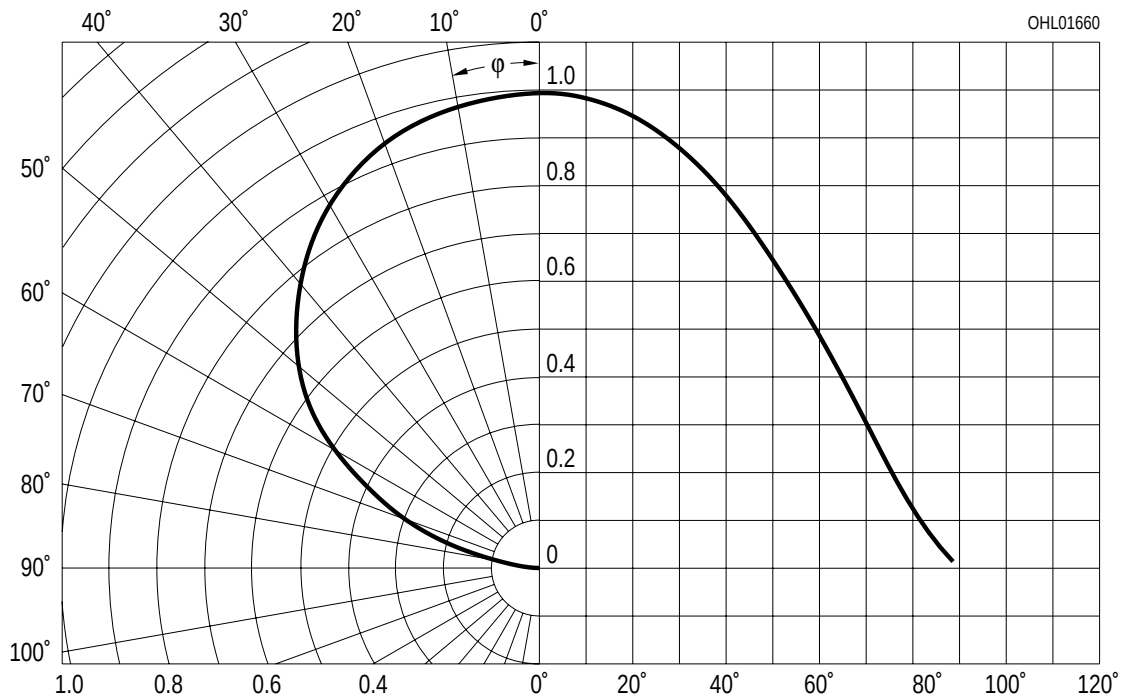
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



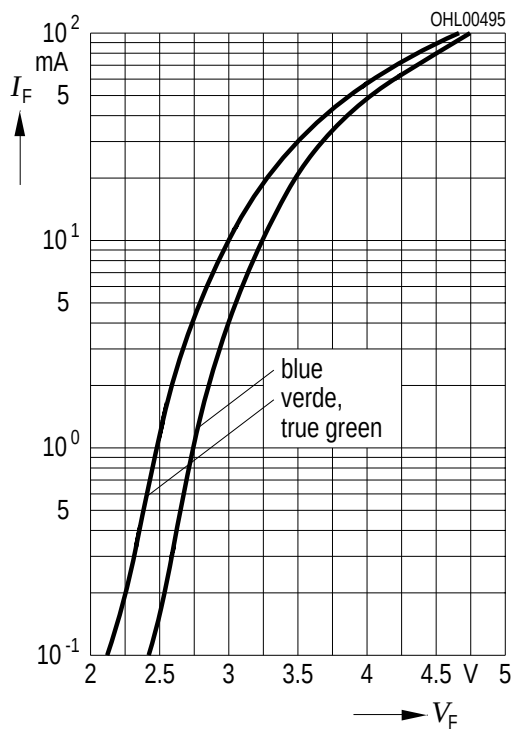
Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

Radiation Characteristic

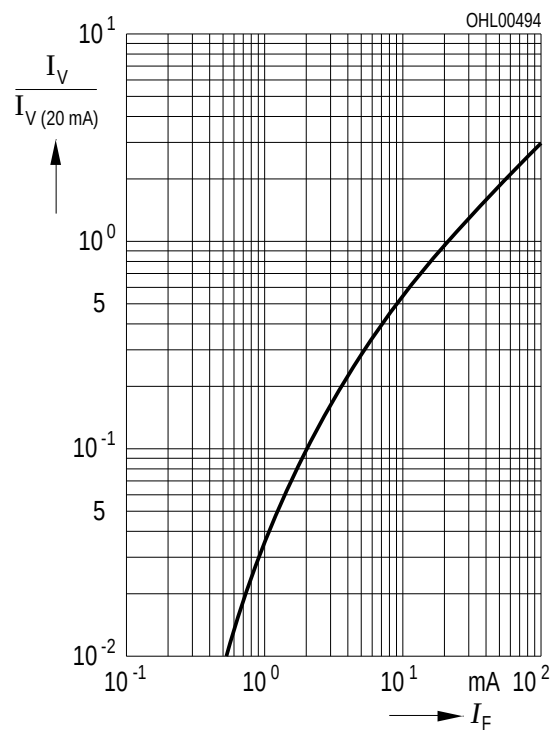


Durchlassstrom $I_F = f(V_F)$

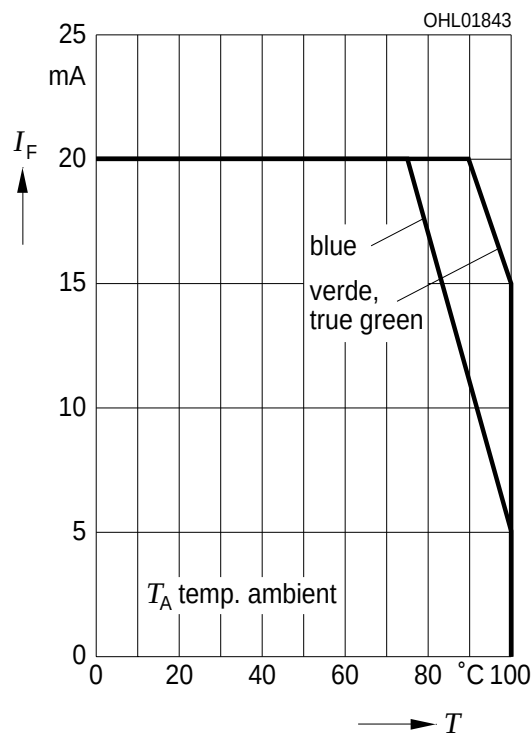
Forward Current

 $T_A = 25\text{ °C}$ Relative Lichtstärke $I_V/I_{V(20\text{ mA})} = f(I_F)$

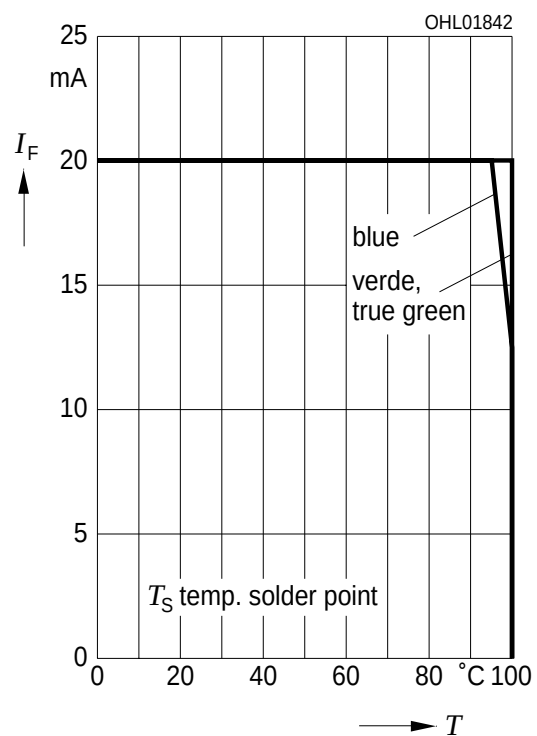
Relative Luminous Intensity

 $T_A = 25\text{ °C}$ Maximal zulässiger Durchlassstrom $I_F = f(T)$

Max. Permissible Forward Current

Maximal zulässiger Durchlassstrom $I_F = f(T)$

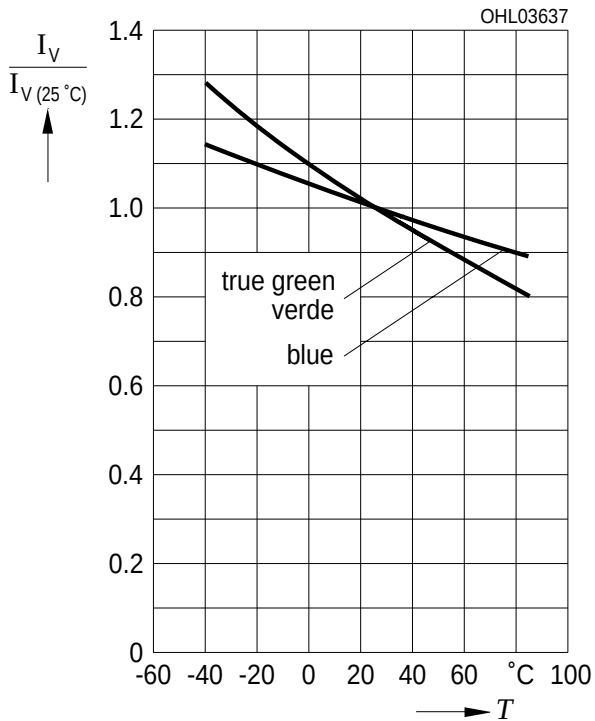
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(25\text{ °C})} = f(T_A)$

Relative Luminous Intensity

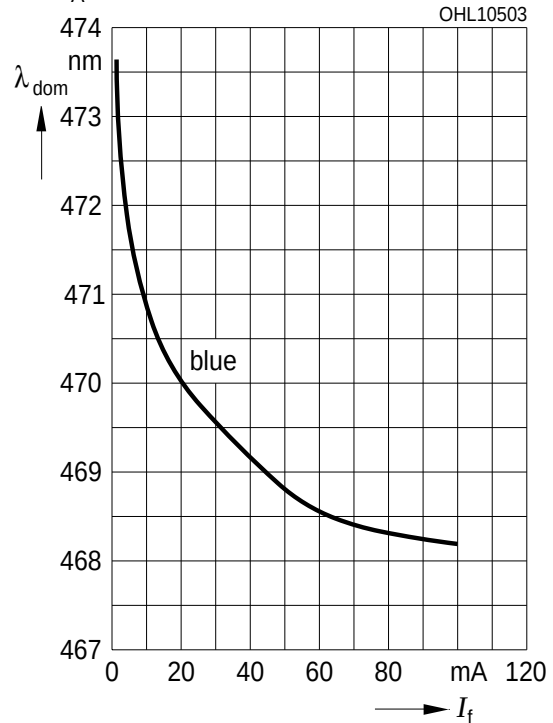
$I_F = 20\text{ mA}$



Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

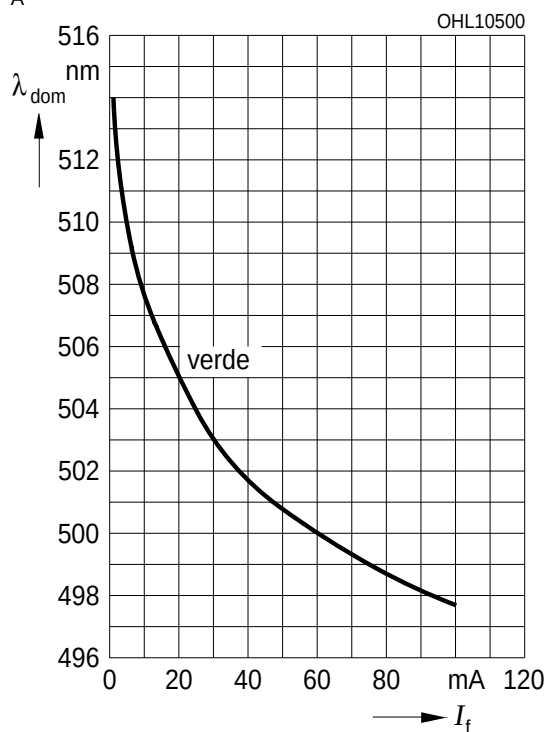
LB, $T_A = 25\text{ °C}$



Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

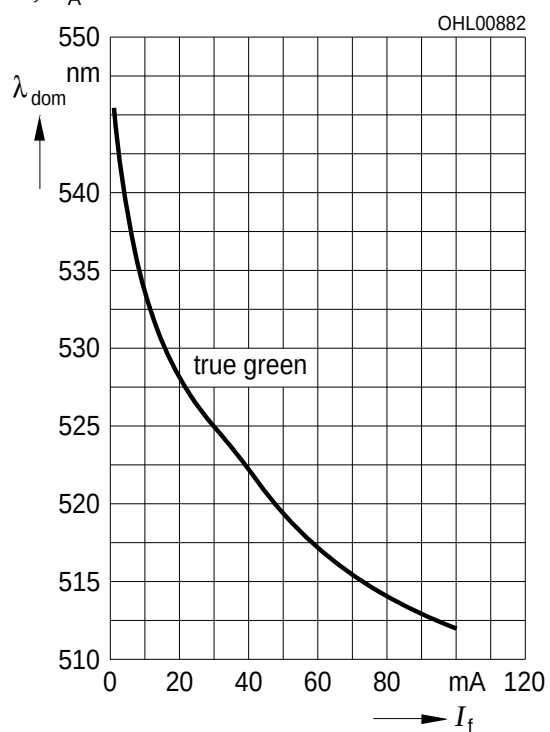
LV, $T_A = 25\text{ °C}$



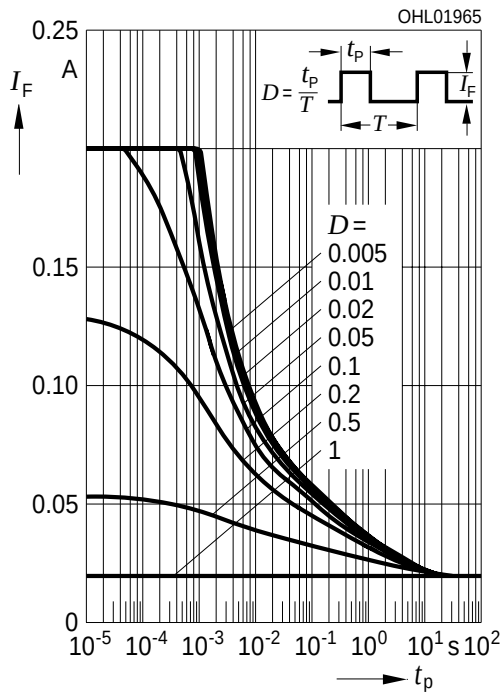
Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

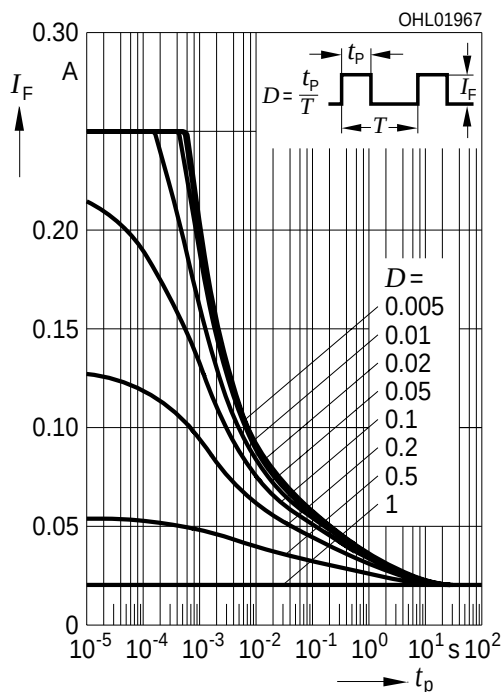
LT, $T_A = 25\text{ °C}$



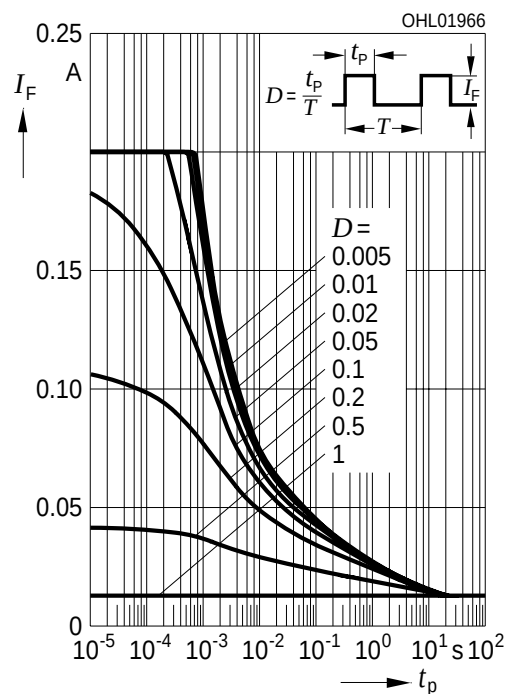
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D = \text{parameter}$, $T_A = 25\text{ °C}$
LB



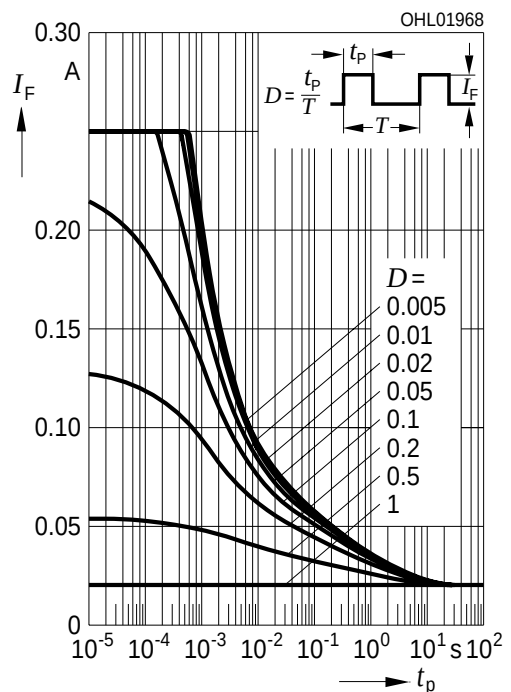
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D = \text{parameter}$, $T_A = 25\text{ °C}$
LV, LT



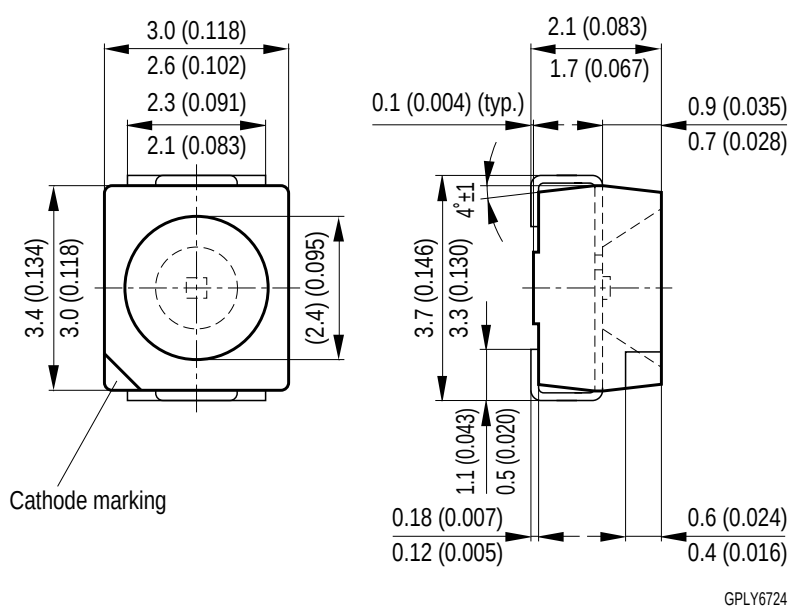
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D = \text{parameter}$, $T_A = 85\text{ °C}$
LB



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D = \text{parameter}$, $T_A = 85\text{ °C}$
LV, LT



Maßzeichnung Package Outlines

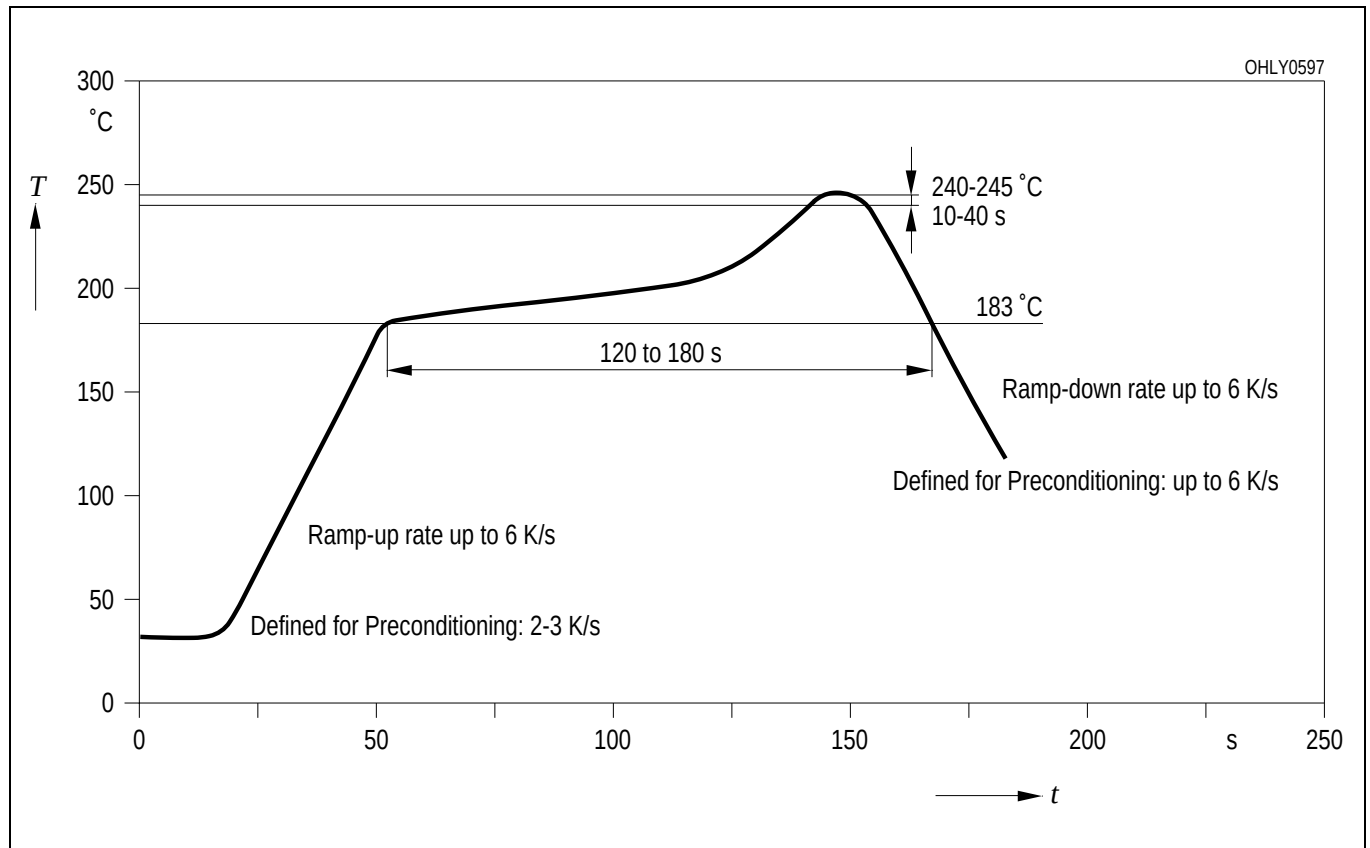


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

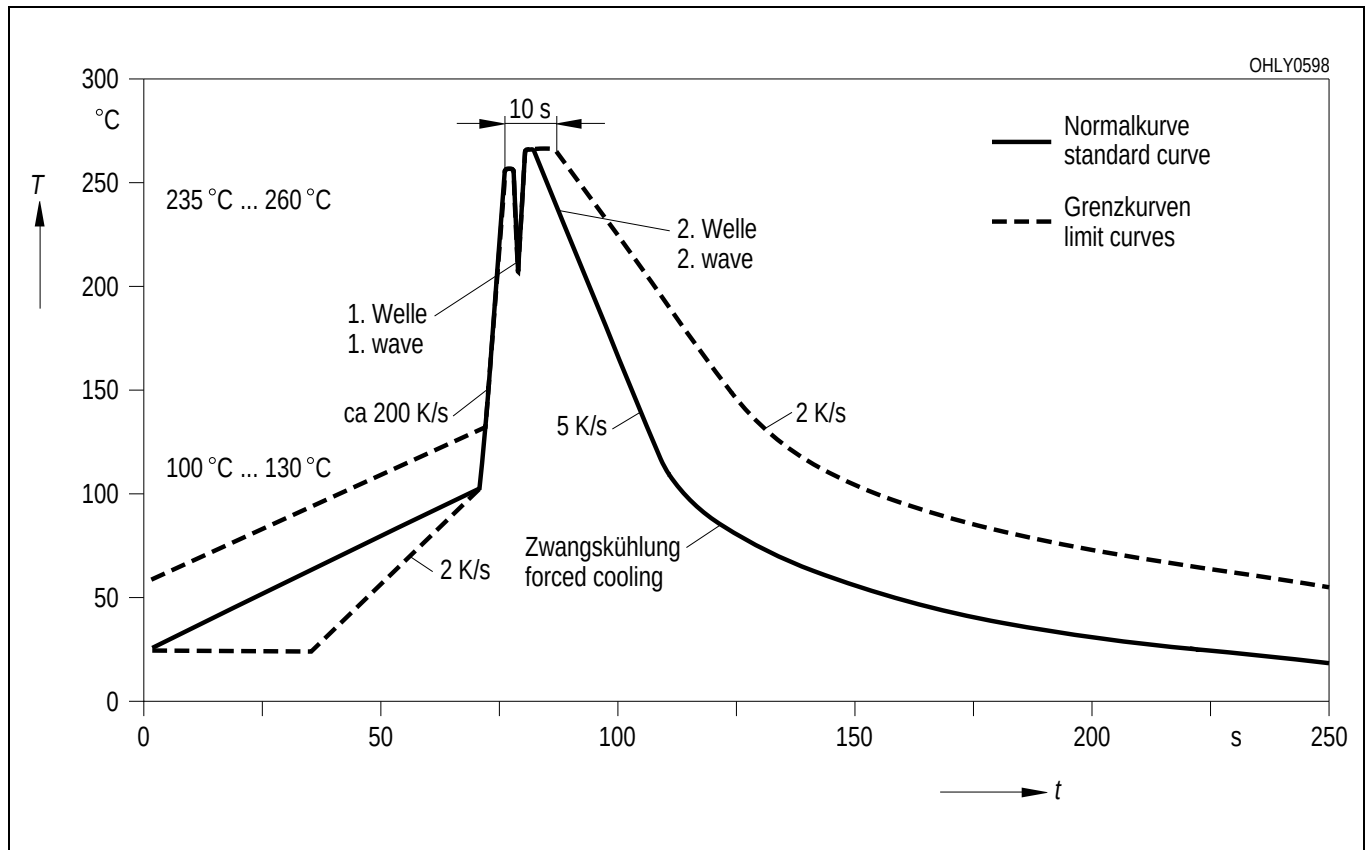
Kathodenkennung: abgeschrägte Ecke
Cathode mark: bevelled edge
Gewicht / Approx. weight: 35 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

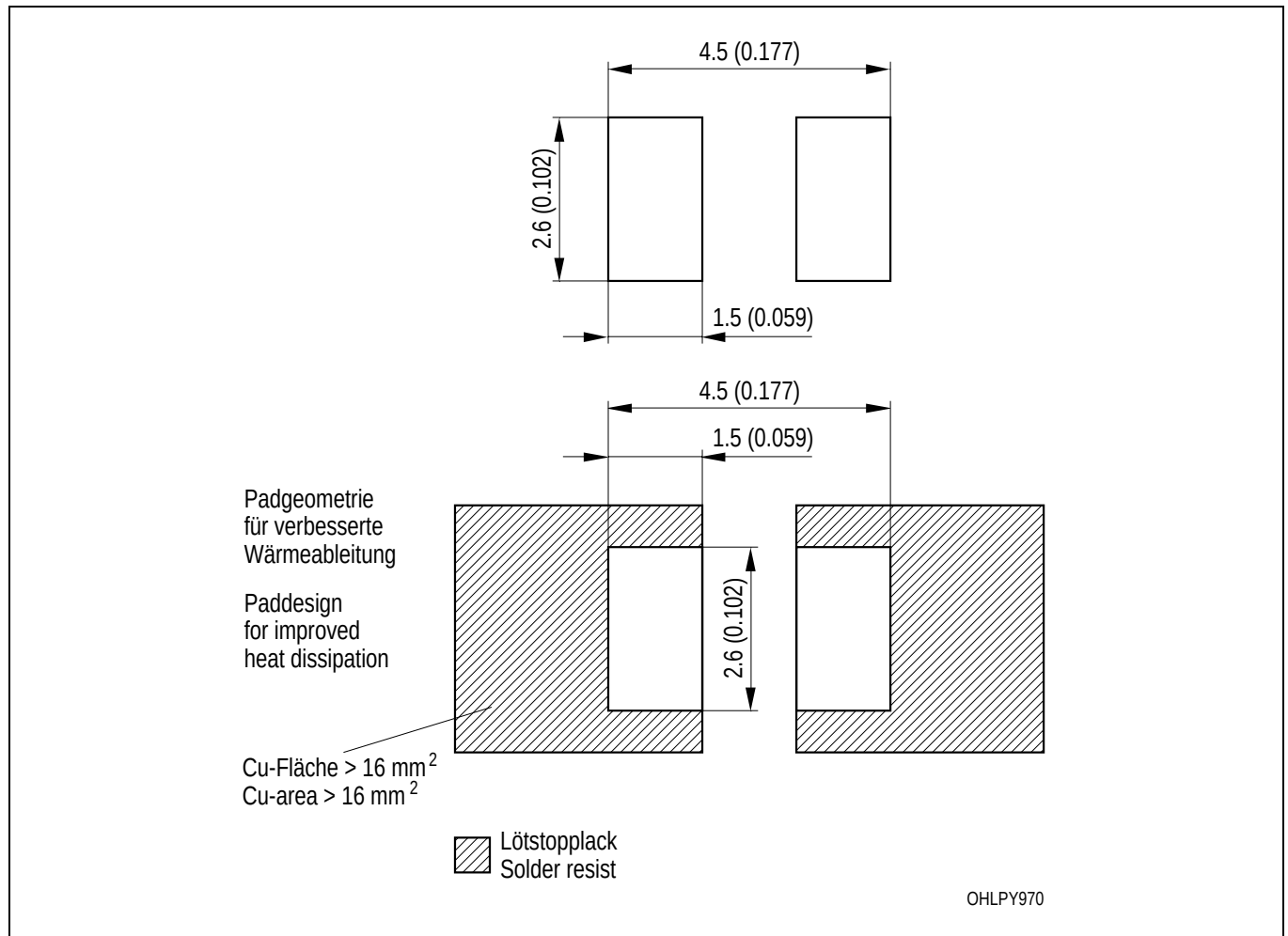
IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



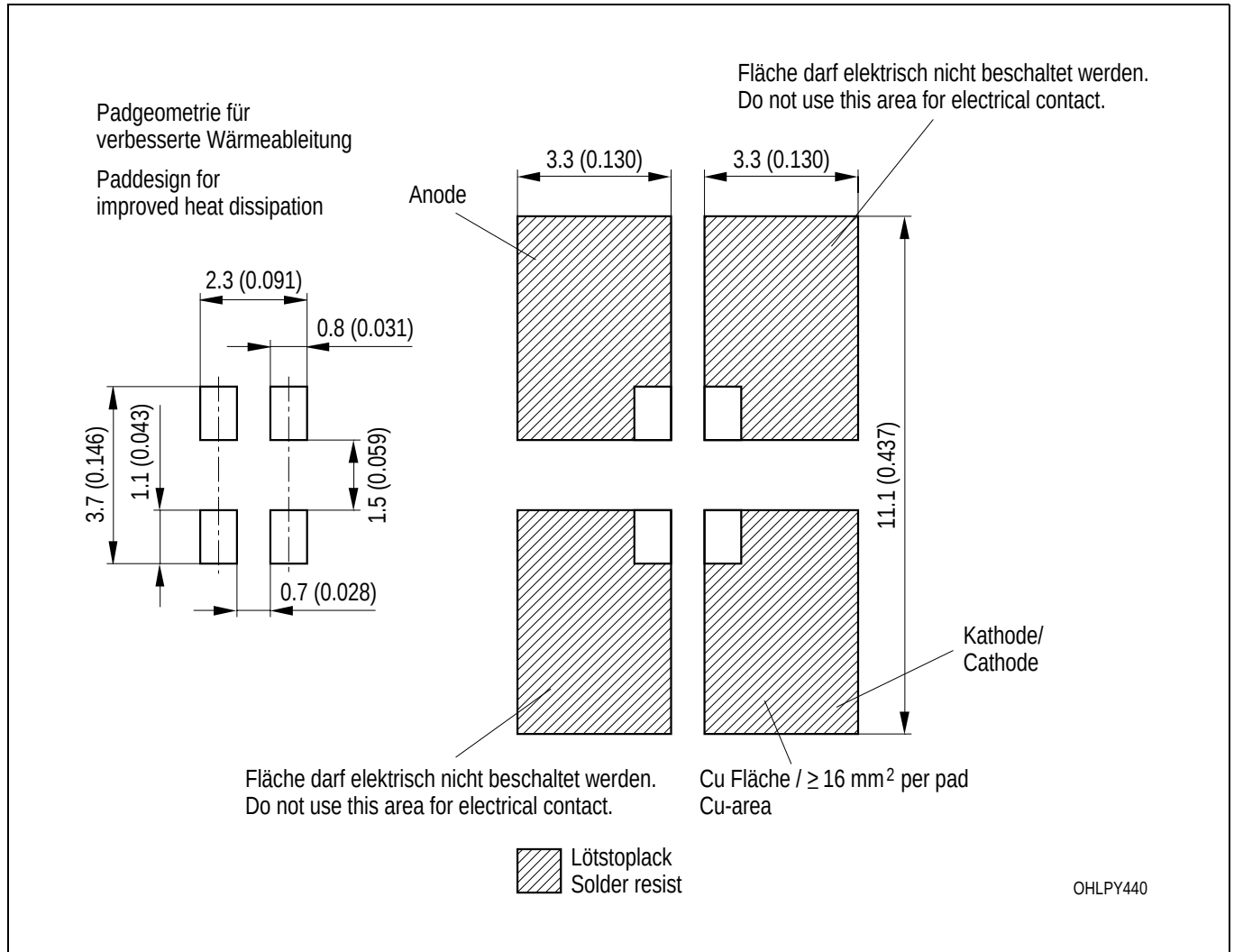
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).
 Gehäuse für Wellenlöten (TTW) geeignet / Package suitable for TTW-soldering

Empfohlenes Lötpaddesign verwendbar für TOPLED® und Power TOPLED®

IR Reflow Löten

Recommended Solder Pad useable for TOPLED® and Power TOPLED®

IR Reflow Soldering



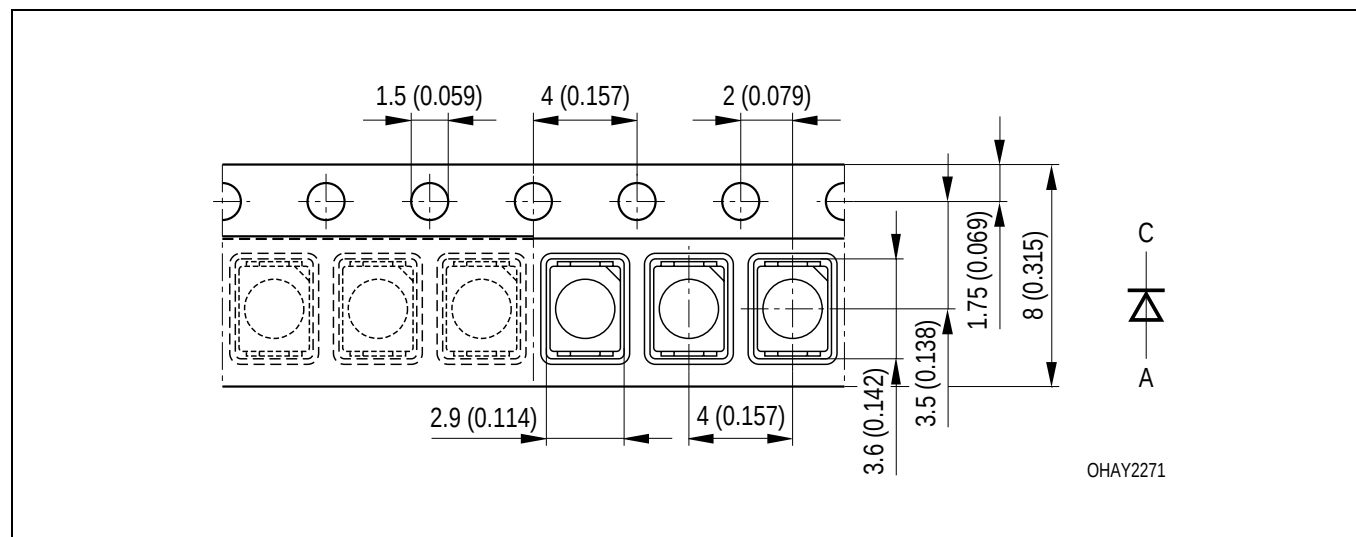
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Gurtung / Polarität und Lage

Verpackungseinheit 2000/Rolle, $\varnothing 180$ mm
oder 8000/Rolle, $\varnothing 330$ mm

Method of Taping / Polarity and Orientation

Packing unit 2000/reel, $\varnothing 180$ mm
or 8000/reel, $\varnothing 330$ mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2003-08-05		Date of change
Previous Version: 2003-06-30		
Page	Subjects (major changes since last revision)	
1	ESD-Festigkeit, ESD-withstand voltage	
4	value (forward voltage)	
3	power consumption from 85 mW to 80 mW	
2	wavelength grouping for blue, true green and verde	
10	change of weight from 40 mg to 35 mg	2002-06-28
15	annotations	2002-07-23
14	recomm. solder pad for TOPLED® and Power TOPLED® (OHLPY440)	2002-08-05
3	reverse voltage (footnote)	2002-08-21
all	verde: not for new designs	2002-11-18
2	new luminous intensity groups for LB T673	2003-03-11
4	values (temperature coefficient of λ_{dom} and V_F)	2003-04-14
7	diagrams max. perm. forward current	2003-06-16
9	new diagrams pulse derating	2003-06-30
1, 2	verde: obsolete	2003-08-05

Published by OSRAM Opto Semiconductors GmbH
Wernerwerkstrasse 2, D-93049 Regensburg

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Attention please!

The information describes the type of component and shall not be considered as assured characteristics. All typical data and graphs are basing on representative samples, but don't represent the production range. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization. If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components ¹ may only be used in life-support devices or systems ² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.